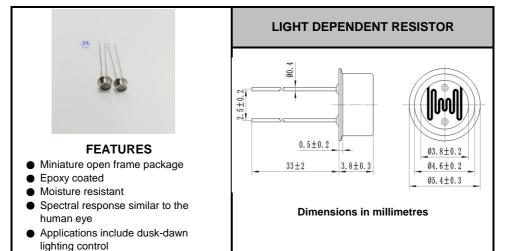


# 晶创和立科技 GL4501

## MINIATURE CADMIUM SULPHIDE PHOTOCONDUCTIVE CELI



### SPECIFICATION AND PERFORMANCE

Model	Vmax (VDC)	Pmax (mW)	Ambient temp(℃)	реак	Light Resistance at 10Lux (KΩ)		Gamm a value at 100- 10Lux	Response Lime (ms)	
								Rise Time	Decay time
GL4501F	100	50	-30~+70	540	5-10	0.5	0.65	30	30

## **Measuring Conditions**

#### KΩ 1000 **Spectral Response** 1. Light resistance: Measured at 10 Lux with standard light A (2854K color temperature) and 2hr Relative Sensitivity (%) illumination at 400-600 lux prior to testing. 100 2. Dark Resistance: 100 Measured 10 senconds after closed 10 lux. 80 3. Gamma Characteristic: Between 10 lux ande 100 lux and given by 60 $\gamma = Ig(R10/R100)$ R10, R100 Cell resistance at 10 lux and 10 40 100 lux The error of y is $\pm 0.1$ . 20 4. Pmax: Max. power dissipation at ambient temperature of 25 °C. 0 400 500 600 700 800 900 1000 10 100lux 5. Vmax: 1 Max. voltage in darkness that may be Wavelength (nm) applied to the cell continuously.

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